NPN High-Voltage Transistor Multicomp





RoHS Compliant

Features

• This product is available in AEC-Q101 Compliant and PPAP Capable also.

Absolute Maximum Ratings (Ta = 25°C Unless otherwise specified)

Parameter	Symbol	Value			Unit
Farameter		MIN	TYP	MAX	Onit
Collector-Base voltage (Open Emitter)	Vсво			180	V
Collector-Emitter voltage (Open Base)	Vceo]		160	V
Collector current	lc]		600	mA
Total power dissipation up to Tamb = 25°C	Ptot			250	m/W
Junction temperature	TJ			150	°C
Collector-emitter saturation voltage	VCEsat]		0.2	V
Emitter-base voltage (open collector)	Vebo			6	V

Thermal Resistance

Parameter	Symbol	Value	Unit
From junction to ambient	Rth (j-a)	500	K/W

Electrical Characteristics at (Ta = 25°C Unless otherwise specified)

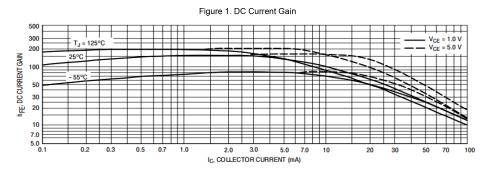
Parameter	Symbol	Test Condition	Value			Unit
Falameter	Symbol	Test Condition		Тур.	Max.	Unit
		IE = 0; Vсв = 120 V				nA
Collector Cutoff Current	Ісво	IE = 0; Vсв = 120 V; T _{amb} = 100 °С			50	μA
Emitter Cutoff Current	Іево	Iс = 0; V _{EB} = 4 V				nA
	V(BR)CEO	Ic = 1 mA; Iв = 0	160			V
Breakdown voltages	V(BR)CBO	Ic = 100 μA; Iε = 0	180			
	V(BR)EBO	Ic = 100 μA; Iε = 0	6			

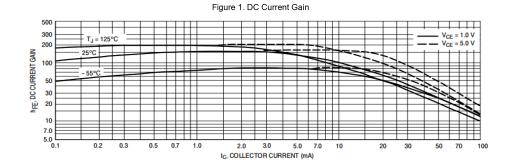


NPN High-Voltage Transistor multicomp

Deveneder	Cumbal	Test Condition	Value			11
Parameter	Symbol	Symbol Test Condition		Тур.	Max.	Unit
Saturation voltages	VCEsat	lc = 10 mA; lв = 1 mA			0.15	
	VBEsat				1	
	VCEsat	Ic = 50 mA: I _B = 5 mA			0.2	
	VBEsat	10 - 50 mA, 18 - 5 mA			1	
DC Current Gain	hfe	Ic = 1 mA; Vce = 5 V	80			
		Ic = 10 mA; Vce = 5 V			250	
		Ic = 50 mA; Vce = 5 V	30			
Small–signal current gain	hfe	Ic = 1 mA; Vce = 10 V; f = 1 kHz	50		200	
Output capacitance at f = 1 MHz	C∘	IE = 0; Vсв = 10 V			6	pF
Input capacitance at f = 1 MHz	Ci	Iс = 0; Vев = 0.5 V			30	
Transition frequency at f = 100 MHz	f⊤	Ic = 10 mA; Vce = 10 V	100		300	MHz

Typical Elecitrical Characteristic Curves

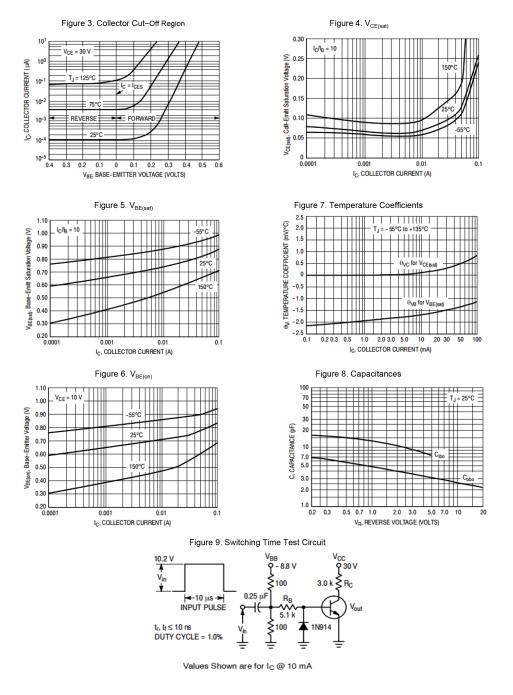






NPN High-Voltage Transistor multicomp

Typical Elecitrical Characteristic Curves

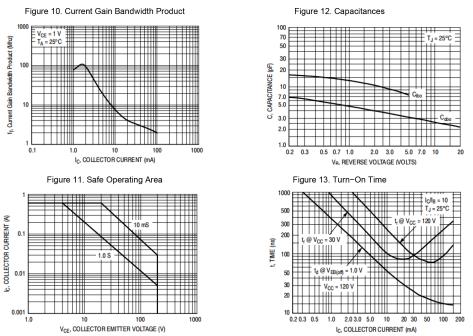


Newark.com/multicomp-pro Farnell.com/multicomp-pro sg.element14.com/b/multicomp-pro

multicomp PRO

NPN High-Voltage Transistor multicomp PRO

Typical Elecitrical Characteristic Curves

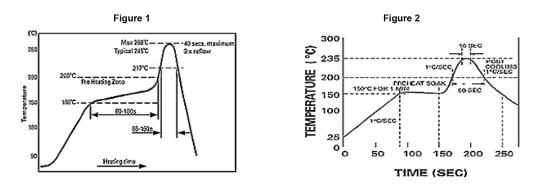


Recommended Reflow Solder Profiles

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

Figure 1 shows the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.





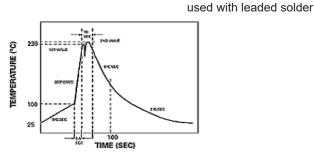
NPN High-Voltage Transistor Multicomp PRO

Profile Feature	Sn-Pb System	Pb-Free System			
Average Ramp-Up Rate	~3°C/second	~3°C/second			
Preheat – Temperature Range – Time	150-170°C 60-180 seconds	150-200°C 60-180 seconds			
Time maintained above: – Temperature – Time	200°C 30-50 seconds	217°C 60-150 seconds			
Peak Temperature	235°C	260°C max.			
Time within +0 -5°C of actual Peak	10 seconds	40 seconds			
Ramp-Down Rate	3°C/second max.	6°C/second max.			

Reflow profiles in tabular form

Recommended Wave Solder Profiles

The Recommended solder Profile For Devices with Pb-free terminal plating where a Pb-free solder is used



Wave Profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~200°C/second	~200°C/second
Heating rate during preheat	Typical 1-2, Max 4°C/sec	Typical 1-2, Max 4°C/Sec
Final preheat Temperature	Within 125°C of Solder Temp	Within 125°C of Solder Temp
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	10 seconds
Ramp-Down Rate	5°C/second max.	5°C/second max.

Part Number Table

Description	Part Number	
High–Voltage Transistor, NPN, 600mA	CMBT5551	

The Recommended solder Profile For Devices

with Pb-free terminal plating used with leaded

solder, or for devices with leaded terminal plating

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